

Quarterly Reliability Monitoring Results

Quarters: Q1/2021 to Q4/2021

Based on structural similarity

Supplier		User Part Number						
Nexperia B.V. Name of Laboratory Assembly reliability labs Based on AEC-Q101 Test		PBHV9040T Part Description						
								Nexperia DHAM Small Signal Bipolar
		SMD package						
		Test Conditions	Duration	# Lots	# Quantity	# Rejects		
			TEST					
	Pre- and Post-Stress							
# E1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below		
		JESD22-A113 Bake Tamb = 125 °C	24 hours					
	PC	Soak Tamb = 85 °C, RH = 85%	168 hours					
# A1	Preconditioning	Reflow soldering	3 cycles	849	61170	0		
	HTRB	MIL-STD-750-1 M1039 Method A Tj = Tjmax, Vr = 100% of max. datasheet						
# B1	Bias	reverse voltage	1000 hours	202	16160	0		
# DI	5.00	Tereise totage	1000 110013	202	10100	0		
	тс	JESD22-A104						
# A4	Temperature Cycling	-65 °C to Tjmax, not to exceed 150°C	1000 cycles	171	13680	0		
		JESD22-A102	•					
	AC	Tamb = 121 °C, RH = 100 %						
# A3 alt	Autoclave	Pressure = 205 kPa (29.7 psia)	96 hours	173	13840	0		
	H3TRB	JESD22-A101						
	High Humidity High	Tamb = 85 °C, RH = 85%, VR = 80 % of		. ==				
# A2 alt	Temperature Reverse Bias		1000 hours	173	13840	0		
	701	MIL-STD-750 Method 1037						
# AF	IOL Intermittent Operating Life	ton = toff, devices powered to insure ΔT_j = 100 °C for 15000 cycles	1000 hours	107	15760	0		
# A5	Internittent Operating Life		1000 hours	197	15760	0		
	RSH	JESD22-A111						
# C8	Resistance to Solder Heat		10 s	135	4050	0		
	SD		10.3	133	1050	v		
# C10	Solderability	J-STD-002		342	3420	0		
	,	d by test chamber set up and does not exceed		342	5420	U		

[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

Calculation of FIT and MTTF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia DHAM	Small Signal Bipolar Transistor	16160	0	0.26	3.81E+09

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